

| Parameter | Ratings | Units |
|---------------------|---------|----------------------|
| Blocking Voltage | 350 | V_P |
| Load Current | 120 | mA_{rms} / mA_{DC} |
| On-Resistance (max) | 35 | Ω |

Features

- 3750V_{rms} Input/Output Isolation
- Low Drive Power Requirements (TTL/CMOS Compatible)
- FCC Compatible
- VDE Compatible
- No EMI/RFI Generation
- Machine Insertable, Wave Solderable
- Surface Mount Tape & Reel Packages Available

Applications

- Telecom Switching
 - Tip/Ring Circuits
 - Modem Switching (Laptop, Notebook, Pocket Size)
 - Hook Switch
 - Dial Pulsing
 - Ground Start
 - Ringing Injection
- Instrumentation
- Multiplexers
- Data Acquisition
- Electronic Switching
- I/O Subsystems
- Meters (Watt-Hour, Water, Gas)
- Medical Equipment-Patient/Equipment Isolation
- Security
- Industrial Controls

Description

LAA110 is a dual 1-Form-A Solid State Relay that has two independently controlled, optically coupled MOSFET switches. The output MOSFET switches and photovoltaic die employ optically coupled MOSFET technology to provide 3750 V_{rms} of input-to-output isolation.

The relay outputs, that use patented OptoMOS architecture, are controlled by a highly efficient infrared LED.

This dual pole OptoMOS relay provides a more compact design solution than discrete single-pole relays in a variety of applications, and saves board space by incorporating both switches in a single 8-Pin package.

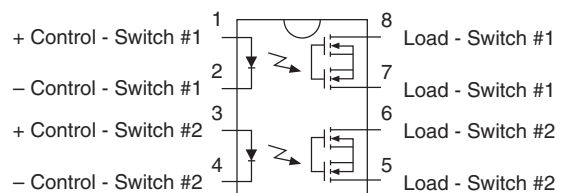
Approvals

- UL Recognized Component: File # E76270
- CSA Certified Component: Certificate # 1175739
- TUV EN 62368-1: Certificate # B 082667 0008

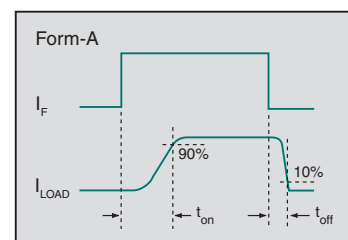
Ordering Information

| Part # | Description |
|-----------|----------------------------------|
| LAA110 | 8-Pin DIP (50/Tube) |
| LAA110S | 8-Pin Surface Mount (50/Tube) |
| LAA110STR | 8-Pin Surface Mount (1,000/Reel) |
| LAA110P | 8-Pin Flat Pack (50/Tube) |
| LAA110PTR | 8-Pin Flat Pack (1,000/Reel) |

Pin Configuration



Switching Characteristics of Normally Open (Form A) Devices



Absolute Maximum Ratings @ 25°C

| Parameter | Ratings | Units |
|--------------------------------------|-------------|------------------|
| Blocking Voltage | 350 | V _P |
| Reverse Input Voltage | 5 | V |
| Input Control Current | 50 | mA |
| Peak (10ms) | 1 | A |
| Input Power Dissipation ¹ | 150 | mW |
| Total Power Dissipation ² | 800 | mW |
| Isolation Voltage, Input to Output | 3750 | V _{rms} |
| Operational Temperature, Ambient | -40 to +85 | °C |
| Storage Temperature | -40 to +125 | °C |

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

¹ Derate linearly 1.33 mW / °C

² Derate output power linearly 6.67 mW / °C

Electrical Characteristics @ 25°C

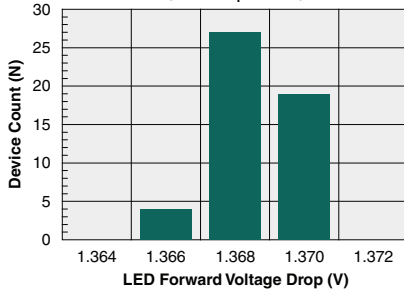
| Parameter | Conditions | Symbol | Min | Typ | Max | Units |
|-------------------------------------|--------------------------------------------------|-------------------|-----|------|------|--------------------------------------|
| Output Characteristics | | | | | | |
| Blocking Voltage | I _L =1μA | V _{DRM} | 350 | - | - | V |
| Load Current | | | | | | |
| Continuous ¹ | - | I _L | - | - | 120 | mA _{rms} / mA _{DC} |
| Peak | t=10ms | I _{LPK} | - | - | ±350 | mA _P |
| On-Resistance ² | I _L =120mA | R _{ON} | - | 25 | 35 | Ω |
| Off-State Leakage Current | V _L =350V _P | I _{LEAK} | - | - | 1 | μA |
| Switching Speeds | | | | | | |
| Turn-On | I _F =5mA, V _L =10V | t _{on} | - | - | 3 | ms |
| Turn-Off | | t _{off} | - | - | 3 | ms |
| Output Capacitance | I _F =0mA, V _L =50V, f=1MHz | C _{OUT} | - | 25 | - | pF |
| Input Characteristics | | | | | | |
| Input Control Current to Activate | I _L =120mA | I _F | - | - | 5 | mA |
| Input Control Current to Deactivate | - | - | 0.4 | 0.7 | - | mA |
| Input Voltage Drop | I _F =5mA | V _F | 0.9 | 1.36 | 1.5 | V |
| Reverse Input Current | V _R =5V | I _R | - | - | 10 | μA |
| Common Characteristics | | | | | | |
| Input to Output Capacitance | V _{IO} =0V, f=1MHz | C _{IO} | - | 3 | - | pF |

¹ If both poles operate the load current must be derated so as not to exceed the package power dissipation value.

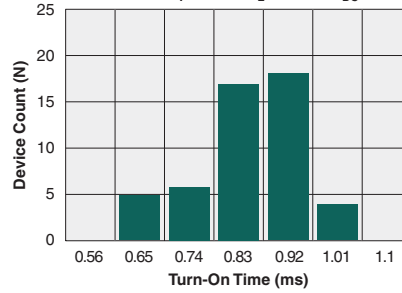
² Measurement taken within 1 second of on-time.

PERFORMANCE DATA*

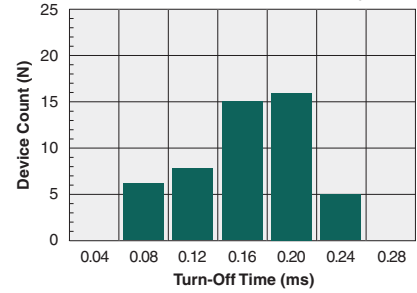
Typical LED Forward Voltage Drop
(N=50, $I_F=5\text{mA}$)



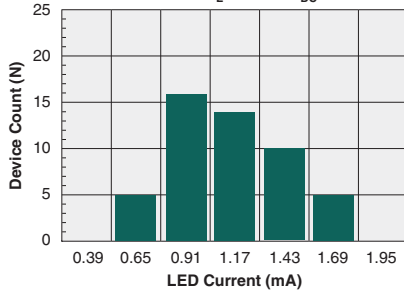
Typical Turn-On Time
(N=50, $I_F=5\text{mA}$, $I_L=120\text{mA}_{DC}$)



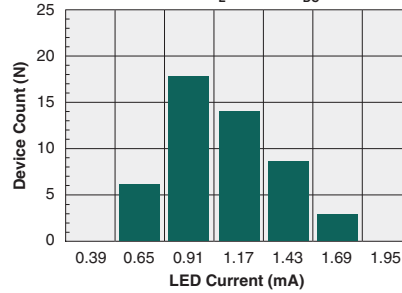
Typical Turn-Off Time
(N=50, $I_F=5\text{mA}$, $I_L=120\text{mA}_{DC}$)



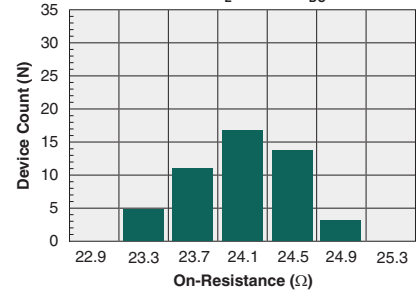
Typical I_F for Switch Operation
(N=50, $I_L=120\text{mA}_{DC}$)



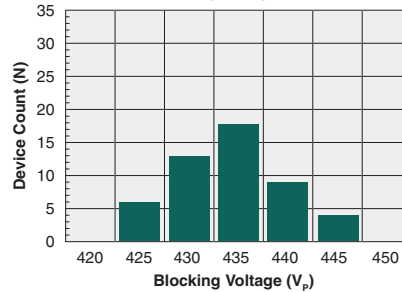
Typical I_F for Switch Dropout
(N=50, $I_L=120\text{mA}_{DC}$)



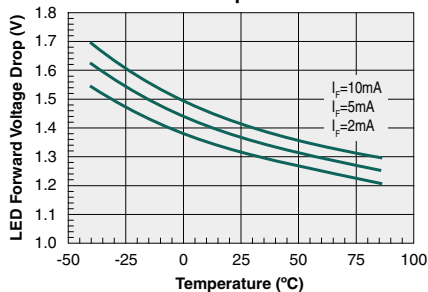
Typical On-Resistance Distribution
(N=50, $I_L=120\text{mA}_{DC}$)



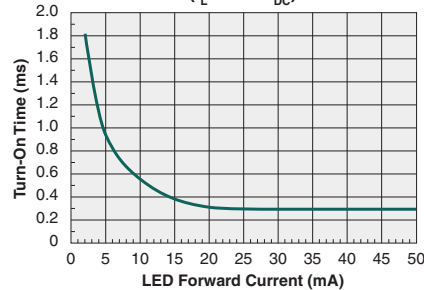
Typical Blocking Voltage Distribution
(N=50)



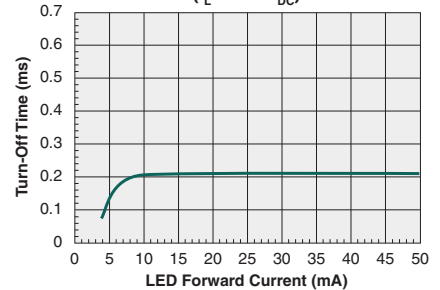
Typical LED Forward Voltage Drop vs. Temperature



Typical Turn-On Time vs. LED Forward Current
($I_L=50\text{mA}_{DC}$)



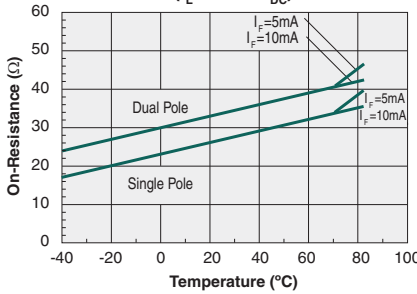
Typical Turn-Off Time vs. LED Forward Current
($I_L=50\text{mA}_{DC}$)



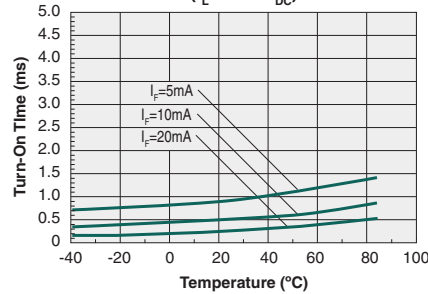
*Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C.

PERFORMANCE DATA*

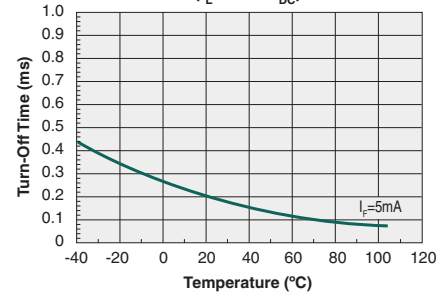
Typical On-Resistance vs. Temperature
($I_L=120mA_{DC}$)



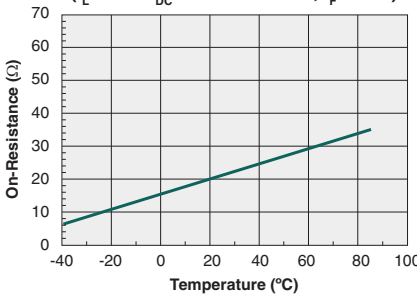
Typical Turn-On Time vs. Temperature
($I_L=50mA_{DC}$)



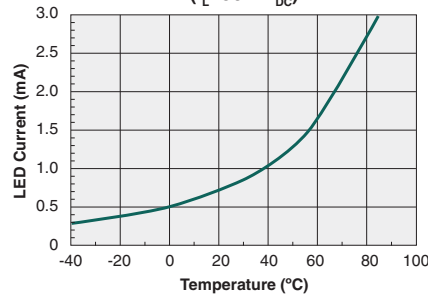
Typical Turn-Off Time vs. Temperature
($I_L=50mA_{DC}$)



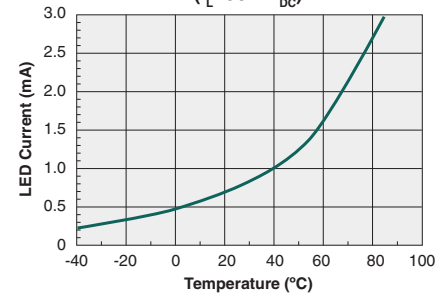
Typical On-Resistance vs. Temperature
($I_L=50mA_{DC}$ Instantaneous, $I_F=5mA$)



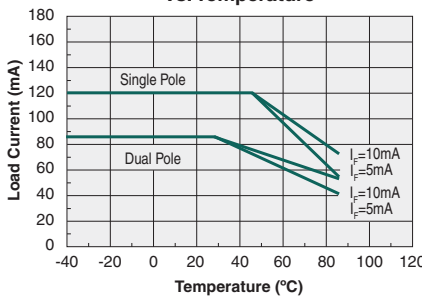
Typical I_F for Switch Operation vs. Temperature
($I_L=50mA_{DC}$)



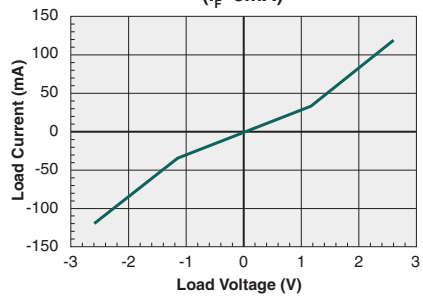
Typical I_F for Switch Dropout vs. Temperature
($I_L=50mA_{DC}$)



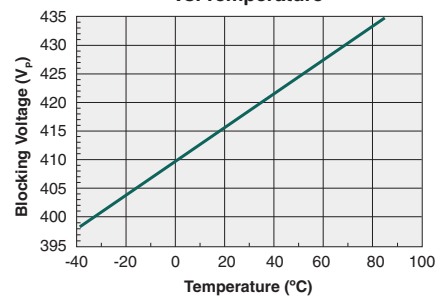
Maximum Load Current vs. Temperature



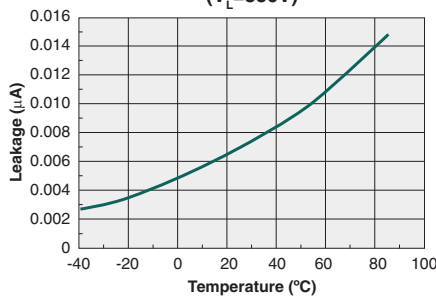
Typical Load Current vs. Load Voltage
($I_F=5mA$)



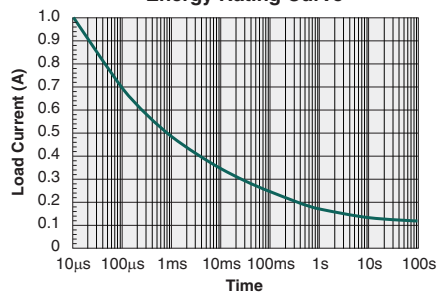
Typical Blocking Voltage vs. Temperature



Typical Leakage vs. Temperature
Measured Across Pins 5&6 or 7&8
($V_L=350V$)



Energy Rating Curve



*Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C.

Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

| Device | Moisture Sensitivity Level (MSL) Classification |
|-------------------|-------------------------------------------------|
| LAA110S / LAA110P | MSL 1 |

ESD Sensitivity



This product is ESD Sensitive, and should be handled according to the industry standard **JESD-625**.

Soldering Profile

Provided in the table below is the **IPC/JEDEC J-STD-020** Classification Temperature (T_C) and the maximum dwell time the body temperature of these surface mount devices may be ($T_C - 5$)°C or greater. The Classification Temperature sets the Maximum Body Temperature allowed for these devices during reflow soldering processes.

| Device | Classification Temperature (T_C) | Dwell Time (t_p) | Max Reflow Cycles |
|---------|--------------------------------------|----------------------|-------------------|
| LAA110S | 250°C | 30 Seconds | 3 |
| LAA110P | 260°C | 30 seconds | 3 |

For through-hole devices, the maximum pin temperature and maximum dwell time through all solder waves is provided in the table below. Dwell time is the interval beginning when the pins are initially immersed into the solder wave until they exit the solder wave. For multiple waves, the dwell time is from entering the first wave until exiting the last wave. During this time, pin temperatures must not exceed the maximum temperature given in the table below. Body temperature of the device must not exceed the limit shown in the table below at any time during the soldering process.

| Device | Maximum Pin Temperature | Maximum Body Temperature | Maximum Total Dwell Time | Wave Cycles |
|--------|-------------------------|--------------------------|--------------------------|-------------|
| LAA110 | 260°C | 250°C | 10 seconds | 1 |

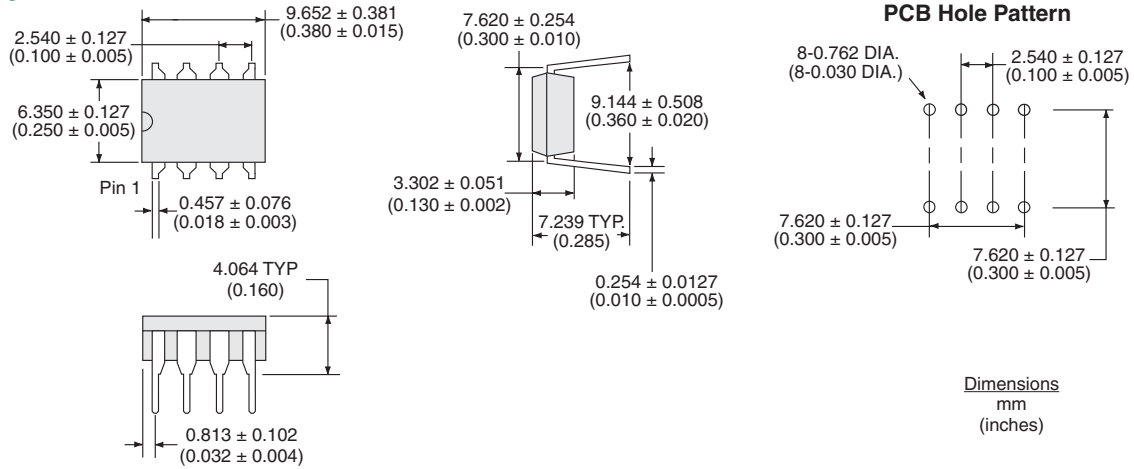
Board Wash

IXYS Integrated Circuits recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

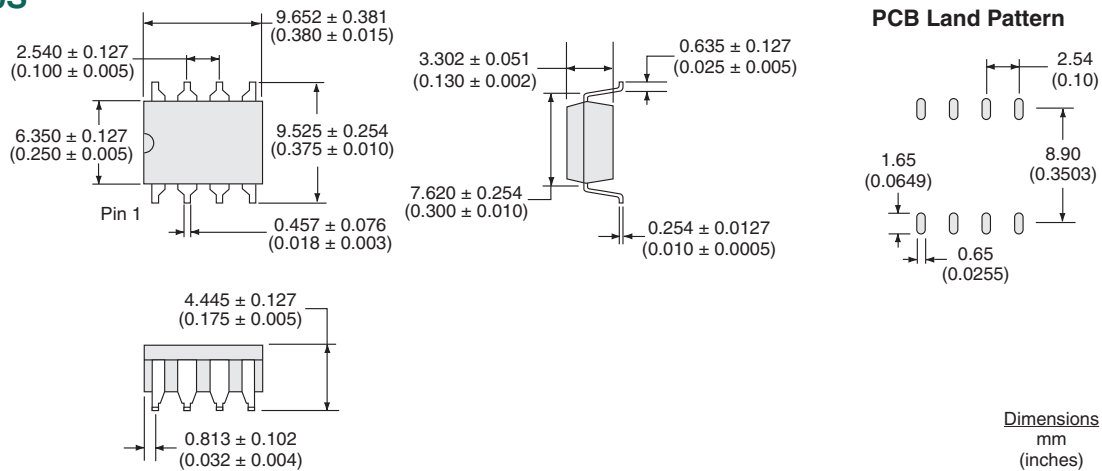


MECHANICAL DIMENSIONS

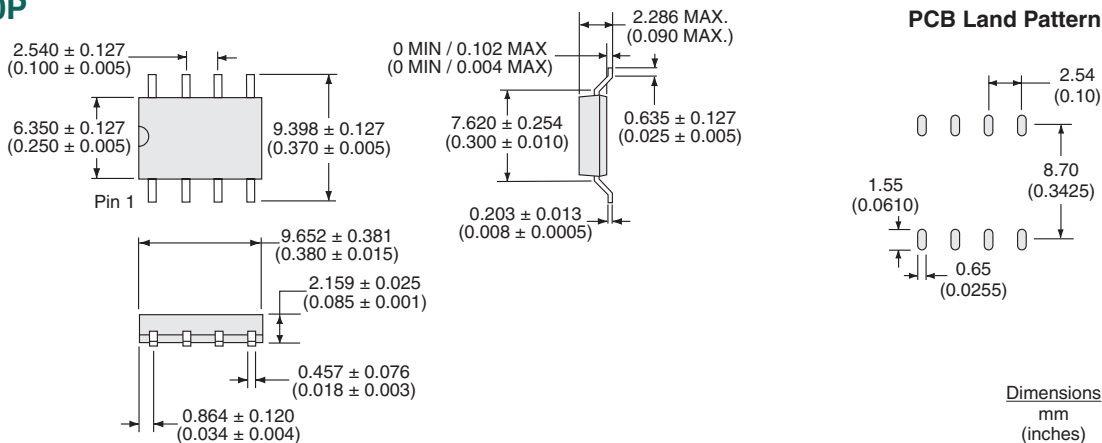
LAA110



LAA110S

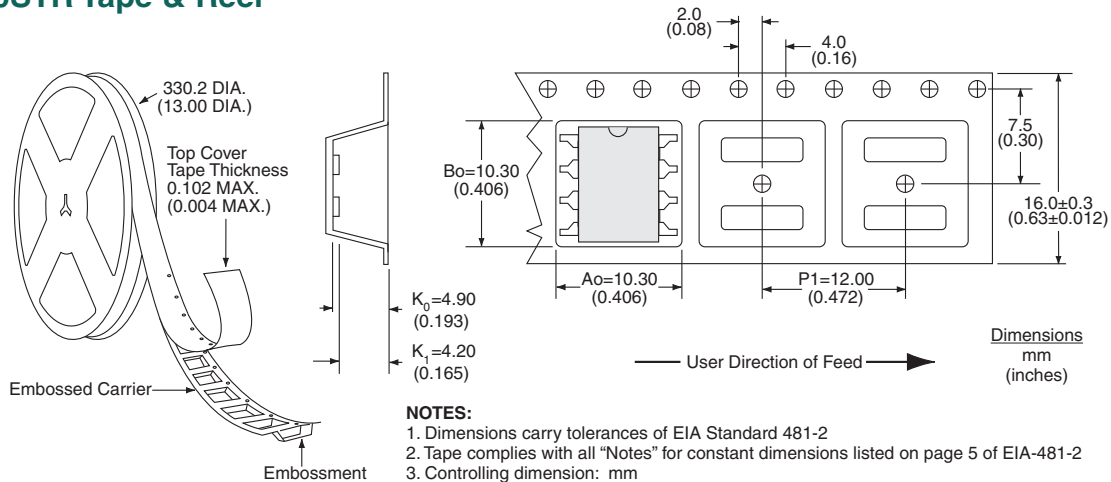


LAA110P

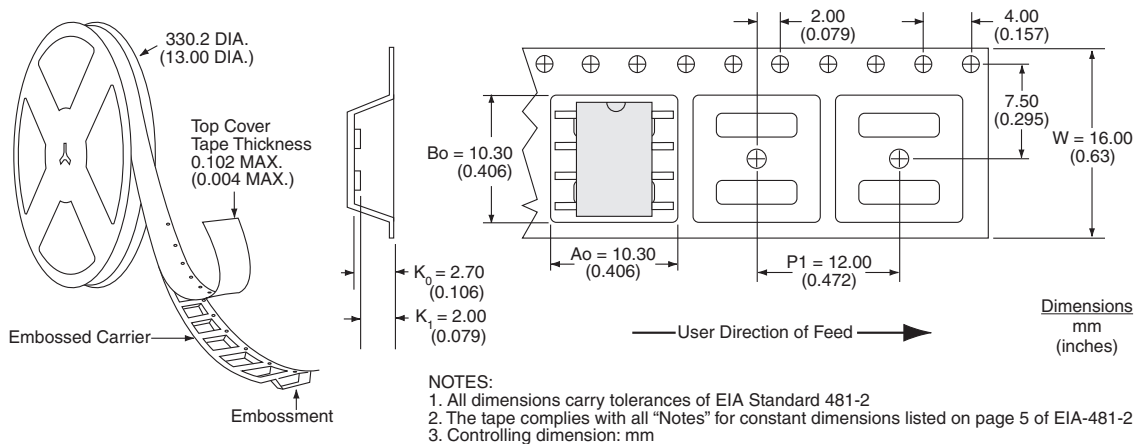


MECHANICAL DIMENSIONS

LAA110STR Tape & Reel



LAA110PTR Tape & Reel



For additional information please visit our website at: <https://www.ixysic.com>